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**Inclosure Material:** 

Plastic

**Overall Length:** 

0.972 inches

# **Overall Height:**

0.110 inches

**Overall Width:** 

0.314 inches

## **Mounting Facility Quantity:**

1

Internal Configuration:

Junction contact

**Mounting Method:** 

Unthreaded hole

Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

150.0 breakdown voltage, collector-to-base, emitter open and 150.0 breakdown voltage, collector-to-emitter, base open and 6.0 breakdown voltage, emitter-to-base, collector open

**Current Rating Per Characteristic:** 

Between 1.50 amperes source cutoff current and 1.50 amperes source cutoff current

### Power Rating Per Characteristic:

1.2 watts small-signal input power, common-collector

**Transfer Ratio:** 

60.0 static forward current transfer ratio, common-emitter and 320.0 static forward current transfer ratio, common-emitter

### Maximum Operating Tempurature Per Measurement Point:

165.0 degrees celsius junction

**Special Features:** 

Junction pattern arrangement: npn

### **Terminal Type And Quantity:**

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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